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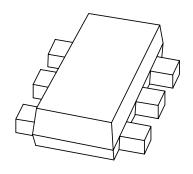
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Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET



PMEG1020EVUltra low V_F MEGA Schottky barrier rectifier

Product data sheet 2003 Jul 15



NXP Semiconductors Product data sheet

Ultra low V_F MEGA Schottky barrier rectifier

PMEG1020EV

FEATURES

• Forward current: 2 A • Reverse voltage: 10 V

Ultra low forward voltage

· Ultra small plastic SMD package.

APPLICATIONS

· Low voltage rectification

• High efficiency DC/DC conversion

• Switch mode power supply

· Inverse polarity protection

· Low power consumption applications.

DESCRIPTION

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection encapsulated in a SOT666 ultra small plastic SMD package.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | cathode |
| 2 | cathode |
| 3 | anode |
| 4 | anode |
| 5 | cathode |
| 6 | cathode |

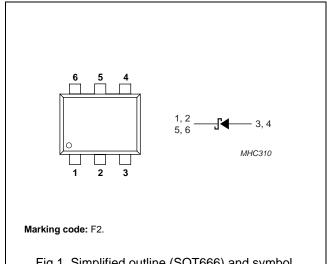


Fig.1 Simplified outline (SOT666) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------------|---|------|------|------|
| V _R | continuous reverse voltage | | _ | 10 | V |
| I _F | continuous forward current | T _{sp} ≤ 55 °C; note 1 | _ | 2 | Α |
| I _{FRM} | repetitive peak forward current | $t_p \le 1$ ms; $\delta \le 0.5$; note 1 | _ | 3.2 | Α |
| I _{FSM} | non-repetitive peak forward current | t _p = 8 ms square wave; note 1 | _ | 9 | Α |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |
| T _{amb} | operating ambient temperature | | -65 | +150 | °C |

Note

1. Only valid if pins 3 and 4 are connected in parallel.

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ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | TYP. | MAX. | UNIT |
|----------------|-------------------|---------------------------------------|------|------|------|
| V _F | forward voltage | see Fig.2; note 1 | | | |
| | | I _F = 0.01 A | 100 | 130 | mV |
| | | I _F = 0.1 A | 164 | 200 | mV |
| | | I _F = 1 A | 255 | 350 | mV |
| | | I _F = 2 A | 306 | 460 | mV |
| I _R | reverse current | see Fig.3 note 2 | | | |
| | | V _R = 5 V | 0.7 | 2 | mA |
| | | V _R = 8 V | 1 | 2.5 | mA |
| | | V _R = 10 V | 1.2 | 3 | mA |
| C _d | diode capacitance | $V_R = 5 V$; $f = 1 MHz$; see Fig.4 | 37 | 45 | pF |

Notes

- 1. Pulse test: $t_p = 300 \ \mu s$; $\delta = 0.02$.
- 2. For Schottky barrier rectifiers thermal runaway has to be considered, as in some applications the reverse power losses (P_R) are a significant part of the total power losses.

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | TINU |
|---------------------|--|------------|-------|------|
| R _{th j-a} | thermal resistance from junction to ambient | note 1 | 405 | K/W |
| | | note 2 | 215 | K/W |
| R _{th j-s} | thermal resistance from junction to solder point | note 3 | 80 | K/W |

Notes

- 1. Refer to SOT666 standard mounting conditions.
- 2. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for cathode 1 cm².
- 3. Solder point of cathode tabs.

Soldering

Reflow soldering is the only recommended soldering method.

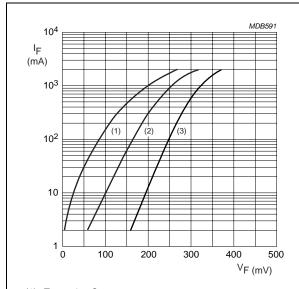
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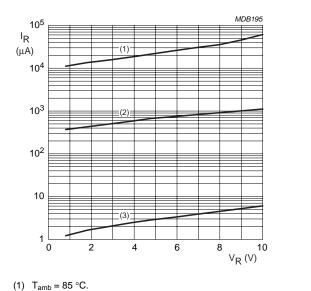
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GRAPHICAL DATA



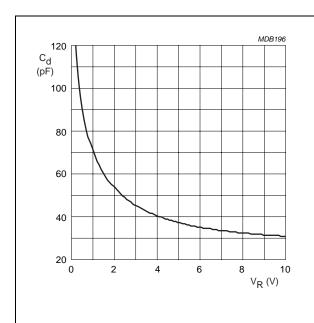
- (1) $T_{amb} = 85 \, ^{\circ}C$.
- (2) $T_{amb} = 25 \, ^{\circ}C$.
- (3) $T_{amb} = -40 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.



- (2) $T_{amb} = 25 \, ^{\circ}C$.
- (3) $T_{amb} = -40 \, ^{\circ}C$.

Fig.3 Reverse current as a function of reverse voltage; typical values.



 $f = 1 \text{ MHz}; T_{amb} = 25 \,^{\circ}\text{C}.$

Fig.4 Diode capacitance as a function of reverse voltage; typical values.

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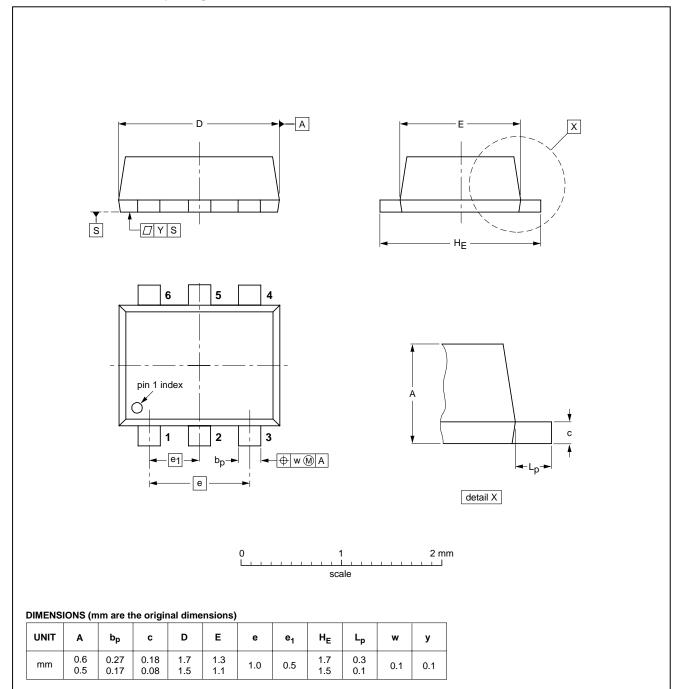
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PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT666



| OUTLINE | REFERENCES | | EUROPEAN | ISSUE DATE | | |
|---------|------------|-------|----------|------------|------------|----------------------------------|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION | 1330E DATE |
| SOT666 | | | | | | -01-01-04 01-08-27 |

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DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
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